

4A 650V SiC Schottky Diode
■ Applications

- Switch Mode Power Supply
- Power Factor Correction
- Solar Inverter
- Uninterruptible Power Supply

■ Features

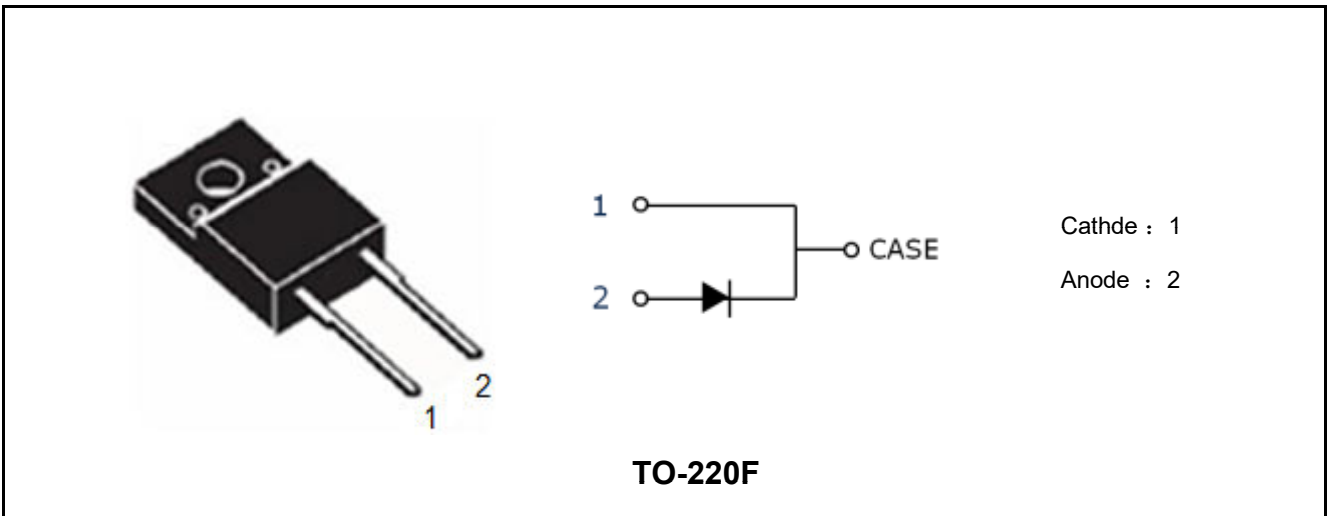
- No Reverse Recovery/ No Forward Recovery
- Temperature Independent Switching Behavior
- Positive Temperature Coefficient on V_F
- Fast Reverse Recovery
- High Surge Current Capability
- 100% UIS and RG Tested

■ Product Summary

V_{RRM}	650	V
$I_F@T_c=150^\circ\text{C}$	4	A
$V_{F,TYP}@T_c=25^\circ\text{C}$	1.4	V
$V_{F,TYP}@T_c=175^\circ\text{C}$	1.7	V
Q_c	8.5	nC

■ Benefits

- Higher System Efficiency
- System Cost and Size Savings
- High Frequency Operation
- Higher System Reliability
- Reduced EMI



Marking	Package	Packaging	Min. package quantity
MF3S04C065	TO-220F	Tube	1000



■ Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	650	V
Surge Peak Reverse Voltage	V_{RSM}	650	V
DC Peak Blocking Voltage	V_R	650	V
Continuous Forward Current	I_F	4	A
Repetitive Peak Forward Surge Current	I_{FSM}	35	A
Power Dissipation	P_D	37.5	W
Junction Temperature	T_J	175	°C
Storage Temperature	T_{stg}	-55-175	°C

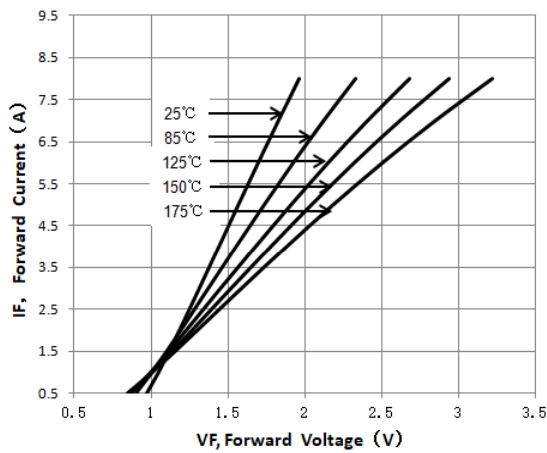
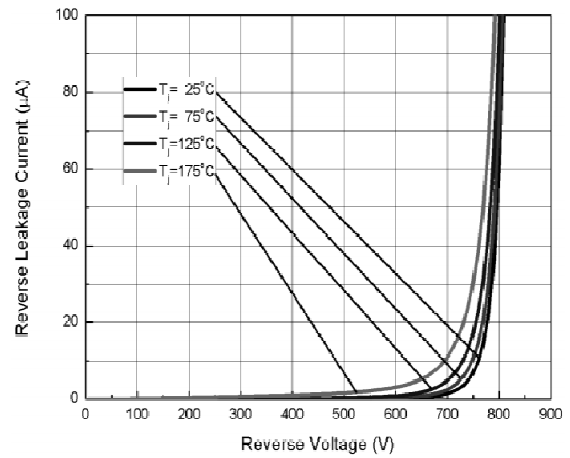
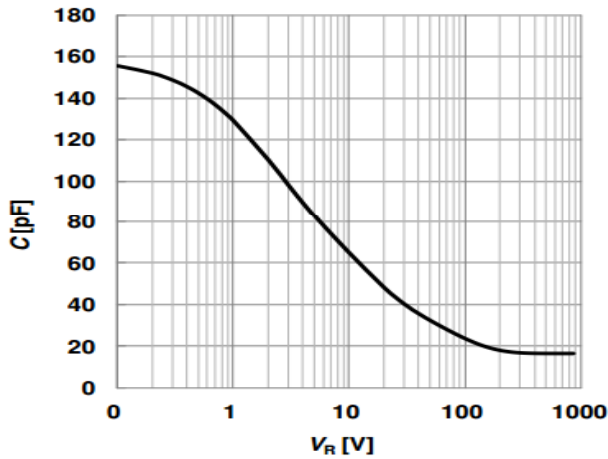
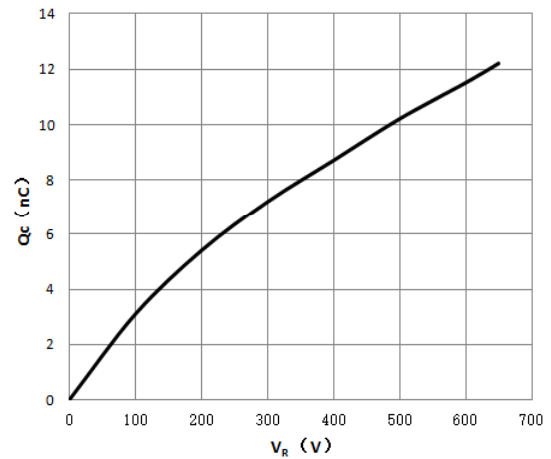
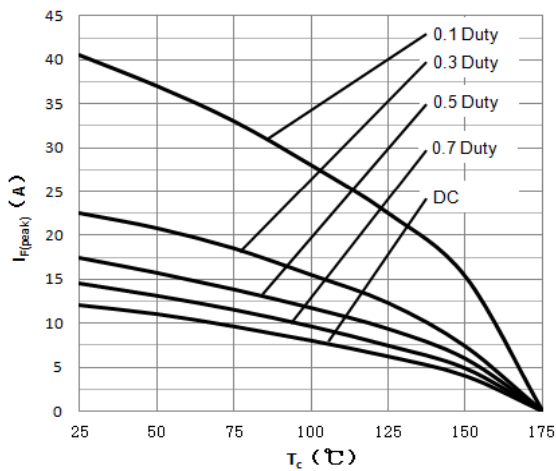
■ Thermal Characteristics

Parameter	Symbol	Max	Unit
Maximum Junction-to-Case	$R_{\theta JC}$	4	°C/W
Maximum Junction-to-Ambient	$R_{\theta JA}$	60	°C/W

■ Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static Parameters						
DC Blocking Voltage	V_{DC}	$I_R=100\mu A$	650	-	-	V
Forward Voltage	V_F	$I_F=4A$	-	1.4	1.7	V
		$I_F=4A, T_J=175^\circ C$	-	1.7	2.2	V
Reverse Current	I_R	$V_R=650V$	-	0.5	10	μA
		$V_R=650V, T_J=175^\circ C$	-	10	50	μA
AC Parameters						
Total Capacitive Charge	Q_C	$I_F=4A, di/dt=500A/\mu s, V_R=400V, T_J=25^\circ C$	-	8.5	-	nC
Total Capacitive	C	$V_R=1V, f=1MHz$	-	135	-	pF
		$V_R=200V, f=1MHz$	-	17	-	
		$V_R=400V, f=1MHz$	-	16	-	



■ Characteristics Curves

Forward Characteristics

Reverse Characteristics

Capacitance

Recovery Charge vs. Reverse Voltage

Current Derating




TO-220F Package Dimensions

Unit: mm

Symbol	Min	Nom	Max	Symbol	Min	Nom	Max
A	4.5		4.9	E1		7	
A1	2.3		2.9	e		2.54	
b	0.45		0.9	e1	1		1.5
b1	1.1		1.7	L	12.5		14.3
b2	1.2		1.4	L1	9.45		10.05
c	0.35		0.9	L2	15		16
D	14.5		17	L3	3.2		4.4
D1	6.1		6.9	ΦP	3		3.3
E	9.6		10.3	Q	2.5		2.9

